











SCAS643I - SEPTEMBER 2000 - REVISED OCTOBER 2017

CDCV304

CDCV304 200-MHz General-Purpose Clock Buffer, PCI-X Compliant

Features

- General-Purpose and PCI-X 1:4 Clock Buffer
- Operating Frequency
 - 0 MHz to 200 MHz General-Purpose
- Low Output Skew: <100 ps
- Distributes One Clock Input to One Bank of Four Outputs
- Output Enable Control that Drives Outputs Low when OE is Low
- Operates from Single 3.3-V Supply or 2.5-V Supply
- **PCI-X Compliant**
- 8-Pin TSSOP Package

2 Description

The CDCV304 is a high-performance, low-skew, general-purpose PCI-X compliant clock buffer. It distributes one input clock signal (CLKIN) to the output clocks (1Y[0:3]). It is specifically designed for use with PCI-X applications. The CDCV304 operates at 3.3 V and 2.5 V and is therefore compliant to the 3.3-V PCI-X specifications.

The CDCV304 is characterized for operation from -40°C to 85°C for automotive and industrial applications.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
CDCV304	TSSOP (8)	3.00 mm × 4.40 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Functional Block Diagram

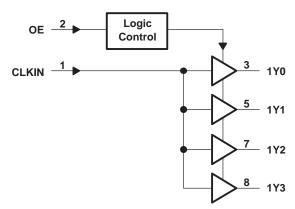




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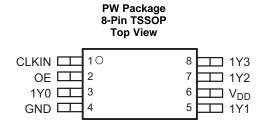
3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision H (February 2011) to Revision I	Page
Changed datasheet layout	1
Added Junction temperature, T _{j, max} 125 °C	
Changes from Revision G (January 2011) to Revision H	Page
Added missing characteristics graphs	6
Changes from Revision F (April 2009) to Revision G	Page
 Added ψ _{JT} and ψ _{JB} specs to the Thermal Information Table and changed R_{θJB} and R_ℓ respectively. 	



4 Pin Configuration and Functions



Pin Functions

PIN		1/0	DESCRIPTION	
NAME	NO.	I/O	DESCRIPTION	
1Y[0:3]	3, 5, 7, 8	0	Buffered output clocks	
CLKIN	1	I	Input reference frequency	
GND	4	Power	Ground	
OE	2	I	Output enable control	
V_{DD}	6	Power	Supply	

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

	MIN	MAX	UNIT
Supply voltage range, V _{DD}	-0.5	4.3	V
Input voltage range, V _I (2) (3)	-0.5	V _{DD} + 0.5	V
Output voltage range, V _O ^{(2) (3)}	-0.5	V _{DD} + 0.5	V
Input clamp current, I _{IK} (V _I < 0 or V _I > V _{DD})	-50	50	mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{DD})	-50	50	mA
Continuous total output current, I_O ($V_O = 0$ to V_{DD})	-50	50	mA
Package thermal impedance, θ_{JA} : PW package		230.5	°C/W
Junction temperature, T _{j, max}		125	°C
Storage temperature range T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(3) This value is limited to 4.6 V maximum.



5.2 Recommended Operating Conditions

		MIN	NOM MAX	UNIT	
Supply voltage, V _{DD}		2.3	3.6	V	
Low-level input voltage, V _{IL}			$0.3 \times V_{DD}$	V	
High-level input voltage, V _{IH}		0.7 x V _{DD}		V	
Input voltage, V _I		0	V_{DD}	V	
Lligh lovel output ourrent I	V _{DD} = 2.5 V		-12	mA	
High-level output current, I _{OH}	V _{DD} = 3.3 V		-24		
Laurianal antoni anno at 1	V _{DD} = 2.5 V		12		
Low-level output current, I _{OL}	V _{DD} = 3.3 V		2.3 3.6 V 0.3 x V _{DD} V 0.7 x V _{DD} V 0 V _{DD} V 1-12 m 12 m 24 m	mA	
Operating free-air temperature, T,	Α.	-40	85	°C	

5.3 Thermal Information

				CDCV304	
	THERMAL METRIC ⁽¹⁾		THERMAL AIR FLOW (CFM)	PW (TSSOP)	UNIT
			1 2011 (01 111)	8 PINS	
			0	149	
	Junction-to-ambient thermal resistance	l link IX	150	142	
		High K	250	138	
Б			500	132	
$R_{\theta JA}$		Low K		230	°C/W
				185	
				170	
				150	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance			43.7	
$R_{\theta JB}$				102	
ΨЈТ	Junction-to-top characterization parameter		1.8		
ΨЈВ	Junction-to-board characterization parameter			100.2	

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V_{IK}	Input voltage	$V_{DD} = 3 V$,	$I_I = -18 \text{ mA}$			-1.2	V
		$V_{DD} = 2.3 V$,	$I_{OH} = -8 \text{ mA}$	1.8			
		$V_{DD} = 2.3 V$,	$I_{OH} = -16 \text{ mA}$	1.5			
V_{OH}	High-level output voltage	V_{DD} = min to max,	$I_{OH} = -1 \text{ mA}$	V _{DD} - 0.2			V
		$V_{DD} = 3 V$,	$I_{OH} = -24 \text{ mA}$	2			
		$V_{DD} = 3 V$,	$I_{OH} = -12 \text{ mA}$	2.4			
		$V_{DD} = 2.3 V$,	$I_{OL} = 8 \text{ mA}$			0.5	V
		$V_{DD} = 2.3 V$,	$I_{OL} = 16 \text{ mA}$			0.7	
V_{OL}	Low-level output voltage	V_{DD} = min to max,	$I_{OL} = 1 \text{ mA}$			0.2	
		$V_{DD} = 3 V$,	$I_{OL} = 24 \text{ mA}$			0.8	
		$V_{DD} = 3 V$,	$I_{OL} = 12 \text{ mA}$			0.55	
	High level output ourrent	$V_{DD} = 3 V$,	$V_O = 1 V$	-50			mA
I _{OH}	High-level output current	$V_{DD} = 3.3 V$,	$V_0 = 1.65 \text{ V}$		-55		ША
	Low lovel output ourrent	$V_{DD} = 3 V$,	V _O = 2 V	60			mA
I _{OL}	Low-level output current	$V_{DD} = 3.3 \text{ V},$	V _O = 1.65 V		70		ША

All typical values are with respect to nominal V_{DD} and T_A = 25°C.



Electrical Characteristics (continued)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP ⁽¹⁾	MAX	UNIT
I_{\parallel}	Input current	$V_I = V_O \text{ or } V_{DD}$				±5	μΑ
	Dunamia gurrant, aga Figura 1	f = 67 MHz,	$V_{DD} = 2.7 \text{ V}$			28	A
IDD	Dynamic current, see Figure 1	f = 67 MHz,	$V_{DD} = 3.6 \text{ V}$			37	mA
Cı	Input capacitance	$V_{DD} = 3.3 \text{ V},$	$V_I = 0 \text{ V or } V_{DD}$		3		pF
Co	Output capacitance	$V_{DD} = 3.3 \text{ V},$	$V_I = 0 V \text{ or } V_{DD}$		3.2		pF

5.5 Timing Requirements

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{clk}	Clock frequency		0		200	MHz

5.6 Switching Characteristics: $V_{DD} = 2.5 \text{ V} \pm 10\%$

 $V_{DD} = 2.5 \text{ V} \pm 10\%$, $C_L = 10 \text{ pF}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Low-to-high propagation delay	See Figure 4 and Figure 5	2	2.9	4.5	
t _{PHL}	High-to-low propagation delay	See Figure 4 and Figure 5	2	3	4.5	ns
t _{sk(o)}	Output skew ⁽²⁾	See Figure 6		50	150	ps
t _r	Output rise slew rate		1.5	2.2	4	V/ns
t _f	Output fall slew rate		1.5	2.2	4	V/ns

5.7 Switching Characteristics: $V_{DD} = 3.3 \text{ V} \pm 10\%$

 $V_{DD} = 3.3 \text{ V} \pm 10\%$, $C_L = 10 \text{ pF}$ (unless otherwise noted)

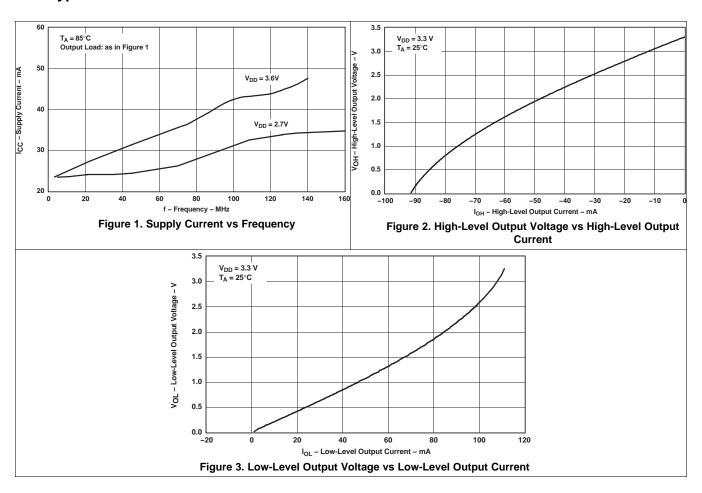
	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t _{PLH}	Low-to-high propagation delay	Con Figure 4 and Figure 5	1.8	2.4	3	
t _{PHL}	High-to-low propagation delay	See Figure 4 and Figure 5	1.8	2.5	3	ns
t _{sk(o)}	Output skew ⁽²⁾			50	100	ps
	Additional and the form install a sector AVO	12 kHz to 5 MHz, f _{out} = 30.72 MHz		63		
t _{jitter}	Additive phase jitter from input to output 1Y0	12 kHz to 20 MHz, f _{out} = 125 MHz		56		fs rms
t _{sk(p)}	Pulse skew	$V_{IH} = V_{DD}, V_{IL} = 0 V$			150	ps
t _{sk(pr)}	Process skew			0.2	0.3	ns
t _{sk(pp)}	Part-to-part skew			0.25	0.4	ns
	Olash kish dan ana Finan 7	66 MHz	6			
t _{high}	Clock high time, see Figure 7	140 MHz	3			ns
	Olash Januarian and Firema 7	66 MHz	6			
t _{low}	Clock low time, see Figure 7	140 MHz	3			ns
t _r	Output rise slew rate ⁽³⁾	V _O = 0.4 V to 2 V	1.5	2.7	4	V/ns
t _f	Output fall slew rate ⁽³⁾	V _O = 2 V to 0.4 V	1.5	2.7	4	V/ns

 $[\]begin{array}{ll} \text{(1)} & \text{All typical values are with respect to nominal V_{DD}.} \\ \text{(2)} & \text{The $t_{sk(o)}$ specification is only valid for equal loading of all outputs.} \end{array}$

 ⁽¹⁾ All typical values are with respect to nominal V_{DD}.
 (2) The t_{sk(o)} specification is only valid for equal loading of all outputs.
 (3) This symbol is according to PCI-X terminology.



5.8 Typical Characteristics





6 Parameter Measurement Information

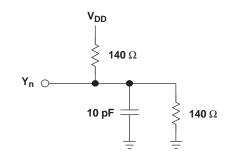


Figure 4. Test Load Circuit

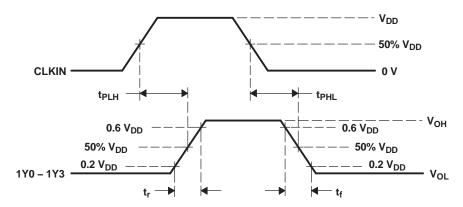


Figure 5. Voltage Waveforms Propagation Delay (tpd) Measurements

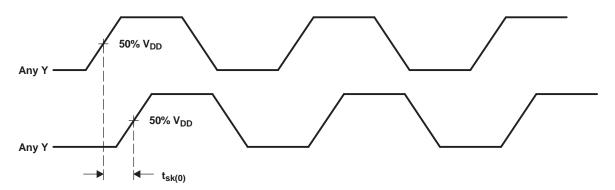
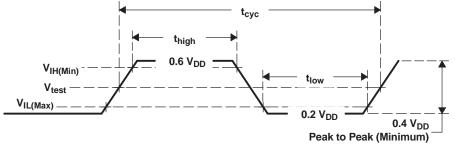


Figure 6. Output Skew

PARAMETER	VALUE	UNIT
V _{IH(Min)}	0.5 V _{DD}	V
V _{IL(Max)}	0.35 V _{DD}	V
V _{test}	$0.4~V_{DD}$	V



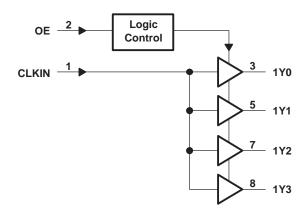
A. All parameters in Figure 7 are according to PCI-X 1.0 specifications.

Figure 7. Clock Waveform



7 Detailed Description

7.1 Functional Block Diagram



7.2 Device Functional Modes

Table 1. Function Table

INP	UTS	OUTPUTS			
CLKIN	CLKIN OE				
L	L	L			
Н	L	L			
L	Н	L			
Н	Н	Н			

Product Folder Links: CDCV304

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8 Device and Documentation Support

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

8.3 Trademarks

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8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
ODOV(00 4D)M	4 OTI) /F	TOOOD	DW		450	D-110 0 0	(6)	1 1 4 0000 LINU INA	40.1- 05	010/004	
CDCV304PW	ACTIVE	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304	Samples
CDCV304PWG4	ACTIVE	TSSOP	PW	8	150	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304	Slan
											Samples
CDCV304PWR	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304	Samples
											Januples
CDCV304PWRG4	ACTIVE	TSSOP	PW	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CKV304	Samples
											Dantiples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF CDCV304:

■ Enhanced Product: CDCV304-EP

NOTE: Qualified Version Definitions:

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

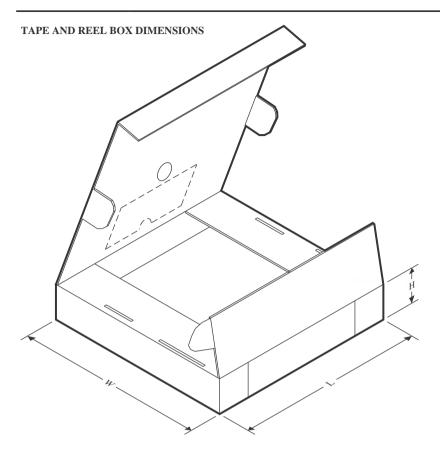


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCV304PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CDCV304PWR	TSSOP	PW	8	2000	356.0	356.0	35.0	

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CDCV304PW	PW	TSSOP	8	150	530	10.2	3600	3.5
CDCV304PWG4	PW	TSSOP	8	150	530	10.2	3600	3.5



SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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